



T-52-07
CD4041UB Types

CMOS Quad True/Complement Buffer

High Voltage Types (20-Volt Rating)

■ CD4041UB types are quad true/complement buffers consisting of n- and p-channel units having low channel resistance and high current (sourcing and sinking) capability. The CD4041UB is intended for use as a buffer, line driver, or CMOS-to-TTL driver. It can be used as an ultra-low power resistor-network driver for A/D and D/A conversion, as a transmission-line driver, and in other applications where high noise immunity and low power dissipation are primary design requirements.

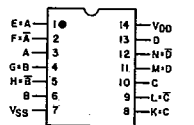
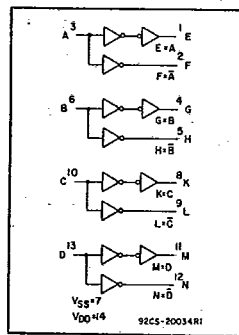
The CD4041UB types are supplied in 14-lead hermetic dual-in-line ceramic packages (D and F suffixes), 14-lead dual-in-line plastic packages (E suffix), 14-lead ceramic flat packages (K suffix), and in chip form (H suffix).

Features:

- Balanced sink and source current; approximately 4 times standard "B" drive
- Equalized delay to true and complement outputs
- 100% tested for quiescent current at 20 V
- Maximum input current of 1 μ A at 18 V over full package temperature range; 100 nA at 18 V and 25°C
- 5-V, 10-V, and 15-V parametric ratings
- Meets all requirements of JEDEC Tentative Standard No. 13B, "Standard Specifications for Description of 'B' Series CMOS Devices"

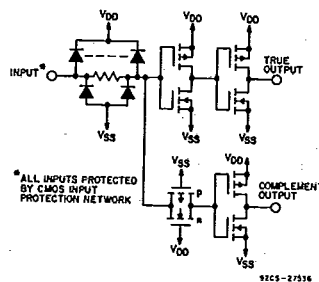
Applications:

- High current source/sink driver
- CMOS-to-DTL/TTL Converter Buffer
- Display driver
- MOS clock driver
- Resistor network driver (Ladder or weighted R)
- Buffer
- Transmission line driver



92CS-20755R1

**TOP VIEW
TERMINAL ASSIGNMENT**



92CS-27536

Fig. 1 - Schematic diagram 1 of 4 buffers.

MAXIMUM RATINGS, Absolute-Maximum Values:

DC SUPPLY-VOLTAGE RANGE, (V_{DD})

Voltages referenced to V_{SS} Terminal -0.5V to +20V
 INPUT VOLTAGE RANGE, ALL INPUTS -0.5V to V_{DD} +0.5V
 DC INPUT CURRENT, ANY ONE INPUT \pm 10mA

POWER DISSIPATION PER PACKAGE (P_D):

For T_A = -55°C to +100°C 500mW
 For T_A = +100°C to +125°C Derate Linearly at 12mW/°C to 200mW

DEVICE DISSIPATION PER OUTPUT TRANSISTOR

FOR T_A = FULL PACKAGE-TEMPERATURE RANGE (All Package Types) 100mW
 OPERATING-TEMPERATURE RANGE (T_A) -55°C to +125°C
 STORAGE TEMPERATURE RANGE (T_{stg}) -65°C to +150°C
 LEAD TEMPERATURE (DURING SOLDERING):
 At distance 1/16 \pm 1/32 Inch (1.59 \pm 0.79mm) from case for 10s max +265°C

RECOMMENDED OPERATING CONDITIONS

For maximum reliability, nominal operating conditions should be selected so that operation is always within the following range:

CHARACTERISTIC	LIMITS		UNITS
	Min.	Max.	
Supply-Voltage Range (For T _A =Full Package-Temperature Range)	3	18	V

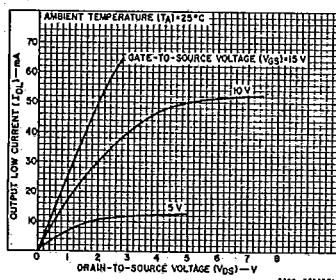


Fig. 2 - Typical output low (sink) current characteristics.

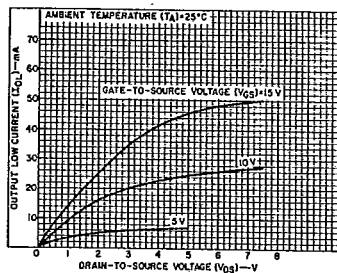


Fig. 3 - Minimum low (sink) current characteristics.

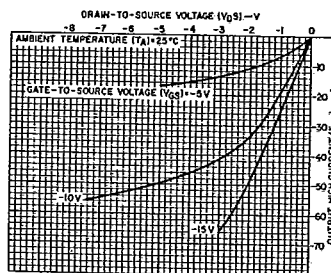


Fig. 4 - Typical output high (source) current characteristics.

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STATIC ELECTRICAL CHARACTERISTICS

CHARACTERISTIC	CONDITIONS			LIMITS AT INDICATED TEMPERATURES (°C)							UNITS
	V _O (V)	V _{IN} (V)	V _{DD} (V)	-55	-40	+85	+125	+25			
								Min.	Typ.	Max.	
Quiescent Device Current I _{DD} Max.	—	0,5	5	1	1	30	30	—	0.02	1	μA
	—	0,10	10	2	2	60	60	—	0.02	2	
	—	0,15	15	4	4	120	120	—	0.02	4	
	—	0,20	20	20	20	600	600	—	0.04	20	
Output Low (Sink) Current, I _{OL} Min.	0.4	0,5	5	2.1	1.8	1.3	1.2	1.6	3.2	—	mA
	0.5	0,10	10	6.25	5.6	4	3.5	5	10	—	
	1.5	0,15	15	24	23	15.5	13	19	38	—	
	4.6	0,5	5	-2.1	-1.8	-1.3	-1.2	-1.6	-3.2	—	
Output High (Source) Current, I _{OH} Min.	2.5	0,5	5	-8.4	-6.7	-5.3	-4.6	-6.4	-12.8	—	mA
	9.5	0,10	10	-6.25	-5.6	-4	-3.5	-5	-10	—	
	13.5	0,15	15	-24	-23	-15.5	-13	-19	-38	—	
	—	—	—	—	—	—	—	—	—	—	
Output Voltage: Low-Level, V _{OL} Max.	—	0,5	5	0.05				—	0	0.05	V
	—	0,10	10	0.05				—	0	0.05	
	—	0,15	15	0.05				—	0	0.05	
Output Voltage: High-Level, V _{OH} Min.	—	0,5	5	4.95				4.95	5	—	V
	—	0,10	10	9.95				9.95	10	—	
	—	0,15	15	14.95				14.95	15	—	
Input Low Voltage, V _{IL} Max.	0.5, 4.5	—	5	1				—	—	1	V
	1.9	—	10	2				—	—	2	
	1.5, 13.5	—	15	2.5				—	—	2.5	
Input High Voltage, V _{IH} Min.	0.5, 4.5	—	5	4				4	—	—	V
	1.9	—	10	8				8	—	—	
	1.5, 13.5	—	15	12.5				12.5	—	—	
Input Current, I _{IN} Max.	—	0,18	18	±0.1	±0.1	±1	±1	—	±10 ⁻⁵	±0.1	μA

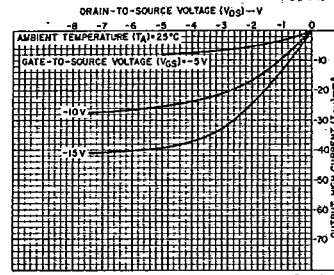


Fig. 5 - Minimum output high (source) current characteristics.

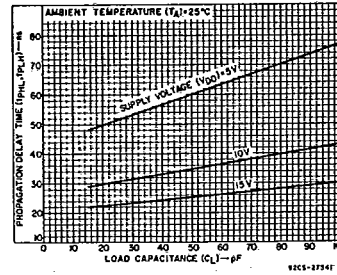


Fig. 6 - Typical propagation delay time vs. load capacitance.

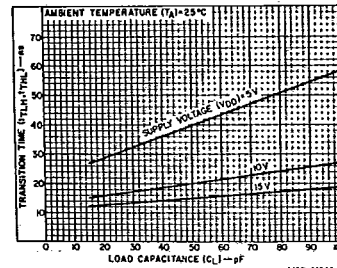


Fig. 7 - Typical transition time vs. load capacitance.

DYNAMIC ELECTRICAL CHARACTERISTICS at T_A = 25°C, Input t_r, t_f = 20 ns, C_L = 50 pF, R_L = 200 kΩ

CHARACTERISTIC	CONDITIONS	LIMITS		UNITS
		V _{DD} Volts	Typ. Max.	
Propagation Delay Time: t _{PHL} , t _{PLH}	Any Input	5	60 120	ns
		10	35 70	
		15	25 50	
Transition Time: t _{THL} , t _{TLL}	Any Input	5	40 80	ns
		10	20 40	
		15	15 30	
Input Capacitance C _{IN}	Any Input	15	22.5	pF

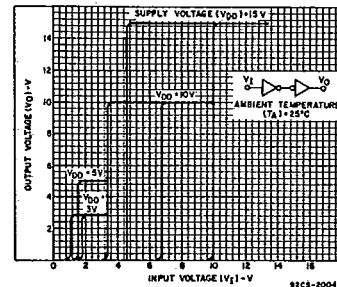


Fig. 8 - Minimum and maximum transfer characteristics - true output.

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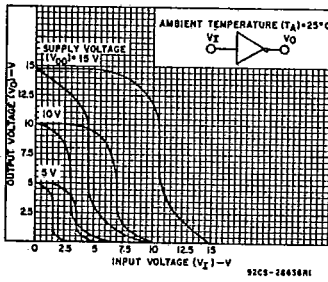


Fig. 9 - Minimum and maximum transfer characteristics - complement output.

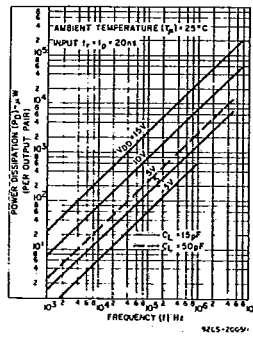


Fig. 11 - Typical power dissipation vs frequency per output pair.

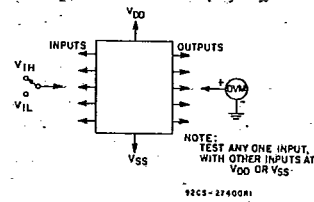


Fig. 13 - Input voltage test circuit.

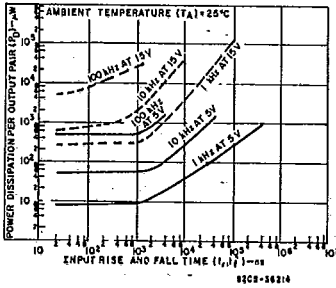


Fig. 10 - Typical power dissipation vs. input rise & fall time per output pair.

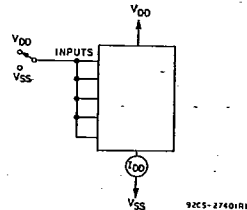


Fig. 12 - Quiescent device current test circuit.

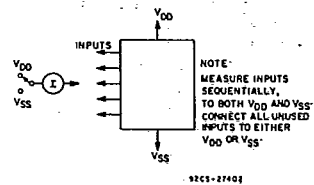
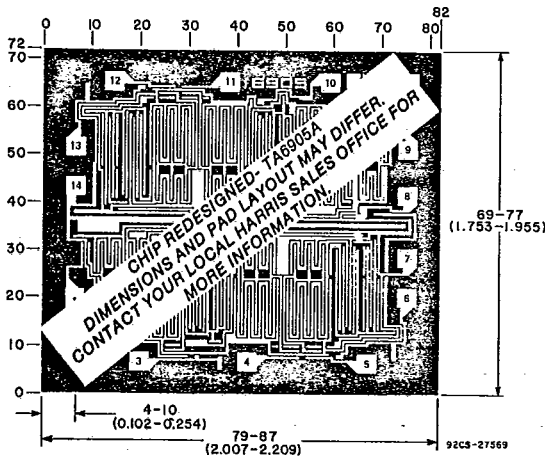


Fig. 14 - Input-leakage-current test circuit.

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Dimensions and pad layout for the CD4041UBH



Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils (10⁻³ inch).